

Quiz 4 (Chapter 5)

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Optic Commu (PAK)

Quiz 4

An InGaAs pin photodiode has the following parameters at 1550 nm: $I_D = 1.0$ nA, $\eta = 0.95$, $R_L = 500 \Omega$, and the surface leakage current is negligible. The incident optical power is 500 nW (-33dBm) and the receiver bandwidth is 150 MHz. Find quantum noise.

Find quantum noise

formula: $\langle i_Q^2 \rangle = 2qI_p B$

let $B = 150$ MHz, $q = 1.6 \times 10^{-19}$ C, $I_p = ?$

formula: $I_p = R P_o = \frac{\eta q \lambda}{hc} \cdot P_o = 5.92 \times 10^{-9}$ A = 0.5927 μ A

then, $\langle i_Q^2 \rangle = 2 \times (1.6 \times 10^{-19} \text{ C}) \times (0.5927 \times 10^{-6} \text{ A}) \times (150 \times 10^6 \text{ Hz})$

$$\langle i_Q^2 \rangle = 2.84496 \times 10^{-17} \text{ A}^2$$

Hence $\langle i_Q^2 \rangle^{1/2}$ is 5.334×10^{-9} A = 5.334 nA